#### MSA-0886

# Cascadable Silicon Bipolar MMIC Amplifier

## AVAGO

### **Data Sheet**

#### **Description**

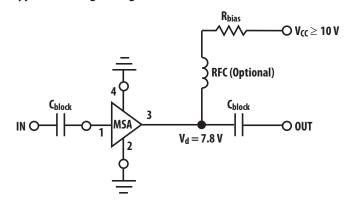
The MSA-0886 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a low cost, surface mount plastic package. This MMIC is designed for use as a general purpose 50  $\Omega$  gain block above 0.5 GHz and can be used as a high gain transistor below this frequency. Typical applications include narrow and moderate band IF and RF amplifiers in commercial and industrial applications.

The MSA-series is fabricated using Avago's 10 GHz  $f_T$ , 25 GHz  $f_{MAX}$ , silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

#### 86 Plastic Package



#### **Typical Biasing Configuration**



#### **Features**

- Lead-free Option Available
- Usable Gain to 5.5 GHz
- High Gain:
  32.5 dB Typical at 0.1 GHz
  22.5 dB Typical at 1.0 GHz
- Low Noise Figure:3.3 dB Typical at 1.0 GHz
- Surface Mount Plastic Package
- Tape-and-Reel Packaging Option Available
- Lead-free Option Available

#### **MSA-0886 Absolute Maximum Ratings**

Parameter	Absolute Maximum [1]		
Drain Current	65 mA		
Power Dissipation [2, 3]	500 mW		
RF Input Power	+13 dBm		
Junction Temperature	150° C		
Storage Temperature	-65° C to 150° C		

nal Resistance <sup>(2)</sup> 140°C/W

- 1. Permanent damage may occur if any of these limits are exceeded.
- T<sub>CASE</sub> = 25° C.
  Derate at 7.1 mW/°C for T<sub>C</sub> > 80° C.

### Electrical Specifications<sup>[1]</sup>, $T_A = 25^{\circ}$ C

<b>Symbol</b> GP	Parameters and Test Conditions: $I_d = 36 \text{ mA}$ , $Z_0 = 36 \text{ mA}$	Units	Min.	Тур.	Max.	
	Power Gain ( $ S_{21} ^2$ )	f = 0.1 GHz f = 1.0 GHz	dB	20.5	32.5 22.5	
VSWR	Input VSWR	f = 0.1 to 3.0 GHz			2.1:1	
	Output VSWR	f = 0.1 to 3.0 GHz			1.9:1	
NF	50 $\Omega$ Noise Figure	f = 1.0 GHz	dB		3.3	
P <sub>1dB</sub>	Output Power at 1 dB Gain Compression	f = 1.0 GHz	dBm		12.5	
IP <sub>3</sub>	Third Order Intercept Point	f = 1.0 GHz			27.0	
t <sub>D</sub>	Group Delay	f = 1.0 GHz	psec		140	
V <sub>d</sub>	Device Voltage		V	6.2	7.8	9.4
dV/dT	Device Voltage Temperature Coefficient		mV/°C		-17.0	

#### **Ordering Information**

Part Numbers	No. of Devices	Comments
MSA-0886-BLK	100	Bulk
MSA-0886-BLKG	100	Bulk
MSA-0886-TR1	1000	7" Reel
MSA-0886-TR1G	1000	7" Reel
MSA-0886-TR2	4000	13" Reel
MSA-0886-TR2G	4000	13" Reel

Note: Order part number with a "G" suffix if lead-free option is desired.

<sup>1.</sup> The recommended operating current range for this device is 20 to 40 mA. Typical performance as a function of current is on the following page.

## MSA-0886 Typical Scattering Parameters [1] (Z $_0$ = 50 $\Omega$ , T $_{\rm A}$ = 25° C, I $_{\rm d}$ = 36 mA)

Freq. GHz	S <sub>11</sub>		S <sub>21</sub>	S <sub>21</sub>		S <sub>12</sub>	S <sub>12</sub>			S <sub>22</sub>	
	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang	k
0.1	0.63	-22	32.5	42.12	160	-36.7	0.015	54	0.62	-24	0.68
0.2	0.56	-41	31.3	36.68	143	-33.9	0.020	50	0.55	-46	0.64
0.4	0.43	-69	28.6	26.94	119	-29.1	0.035	52	0.43	-79	0.69
0.6	0.35	-88	26.4	20.89	104	-27.0	0.045	49	0.34	-103	0.77
0.8	0.30	-104	24.2	16.21	93	-25.3	0.054	50	0.29	-124	0.83
1.0	0.27	-116	22.4	13.20	83	-24.2	0.062	49	0.26	-139	0.87
1.5	0.27	-144	19.2	9.15	65	-21.6	0.083	46	0.23	-172	0.93
2.0	0.31	-166	16.7	6.84	49	-19.5	0.105	41	0.22	163	0.96
2.5	0.35	178	14.8	5.50	38	-17.9	0.128	36	0.21	149	0.96
3.0	0.40	162	12.9	4.41	25	-17.4	0.135	30	0.20	132	1.01
3.5	0.45	149	11.4	3.72	13	-16.8	0.145	25	0.19	124	1.02
4.0	0.51	137	9.9	3.14	1	-16.1	0.157	19	0.18	121	1.01
5.0	0.61	116	7.3	2.31	-22	-15.7	0.164	10	0.17	130	1.00
6.0	0.68	100	4.6	1.69	-42	-15.2	0.173	4	0.23	143	0.95

#### Typical Performance, $T_A = 25^{\circ} C$

(unless otherwise noted)

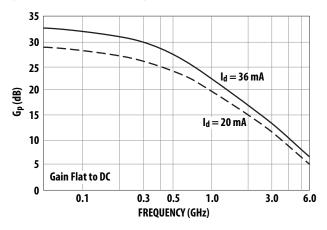


Figure 1. Typical Power Gain vs Frequency,  $I_d = 36 \text{ mA}$ .

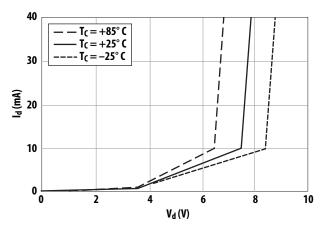


Figure 2. Device Current vs. Voltage.

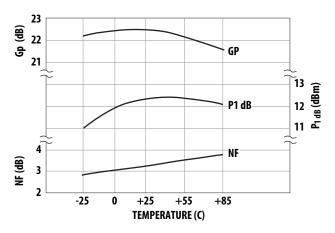


Figure 3. Output Power at 1 dB Gain Compression, NF and Power Gain vs. Case Temperature,  $f=1.0~{\rm GHz}, I_d=36~{\rm mA}.$ 

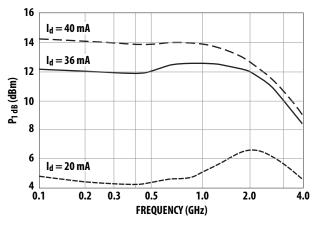


Figure 4. Output Power at 1 dB Gain Compression vs. Frequency.

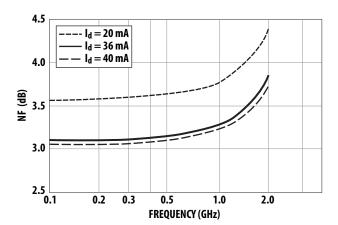
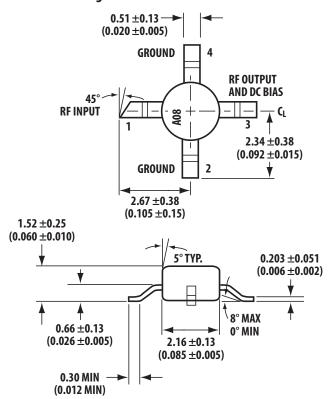


Figure 5. Noise Figure vs. Frequency.

#### **86 Plastic Package Dimensions**



Dimensions are in millimeters (inches)

For product information and a complete list of distributors, please go to our web site: **www.avagotech.com** 

